

SMMBT2907ALT3G Datasheet



| DiGi Electronics Part Number | SMMBT2907ALT3G-DG |
|------------------------------|--|
| Manufacturer | onsemi |
| Manufacturer Product Number | SMMBT2907ALT3G |
| Description | TRANS PNP 60V 0.6A SOT23-3 |
| Detailed Description | Bipolar (BJT) Transistor PNP 60 V 600 mA 200MHz 3 00 mW Surface Mount SOT-23-3 (TO-236) |
| | |

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|--|--|
| SMMBT2907ALT3G | onsemi |
| Series: | Product Status: |
| | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| PNP | 600 mA |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, lc: |
| 60 V | 1.6V @ 50mA, 500mA |
| Current - Collector Cutoff (Max): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 10nA (ICBO) | 100 @ 150mA, 10V |
| Power - Max: | Frequency - Transition: |
| 300 mW | 200MHz |
| Operating Temperature: | Mounting Type: |
| -55°C ~ 150°C (TJ) | Surface Mount |
| Package / Case: | Supplier Device Package: |
| TO-236-3, SC-59, SOT-23-3 | SOT-23-3 (TO-236) |
| Base Product Number: | |
| SMMBT2907 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.21.0075 | |

onsemi

General Purpose Transistors

PNP Silicon

MMBT2907AL, SMMBT2907AL

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|-----------------------------------|------------------|-------|------|
| Collector – Emitter Voltage | V _{CEO} | -60 | Vdc |
| Collector-Base Voltage | V _{CBO} | -60 | Vdc |
| Emitter-Base Voltage | V _{EBO} | -5.0 | Vdc |
| Collector Current – Continuous | Ι _C | -600 | mAdc |
| Collector Current – Peak (Note 3) | I _{CM} | -1200 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation – FR–5 Board (Note 1) @T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation – Alumina Substrate, (Note 2) @T _A = 25°C Derate above 25°C | P _D | 300 2.4 | m₩ m₩/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Total Device Dissipation – Heat Spreader or equivalent, (Note 4) @T _A = 25°C | P _D | 350 | mW |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 357 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

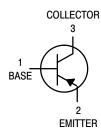
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

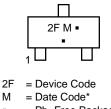
3. Reference SOA curve.

4. Heat Spreader or equivalent = 450 mm², 2 oz.





MARKING DIAGRAM



= Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|-----------|-----------------------|
| MMBT2907ALT1G | SOT-23 | 3000 / Tape & |
| SMMBT2907ALT1G | (Pb-Free) | Reel |
| MMBT2907ALT3G | SOT-23 | 10,000 / Tape & |
| SMMBT2907ALT3G | (Pb-Free) | Reel |

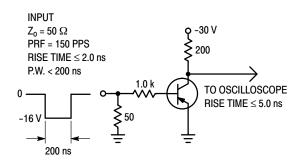
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit |
|---|--|----------------------|-------------------------------|--------------------|------|
| OFF CHARACTERISTICS | | | | | |
| $\label{eq:collector} \begin{array}{l} \mbox{Collector}-\mbox{Emitter Breakdown Voltage (Not (I_C = -1.0 \mbox{ mAdc}, I_B = 0) \\ (I_C = -10 \mbox{ mAdc}, I_B = 0) \end{array}$ | e 5) | V _{(BR)CEO} | -60 -60 | | Vdc |
| Collector-Base Breakdown Voltage (I _C = | = -10 μAdc, I _E = 0) | V _{(BR)CBO} | -60 | - | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = -$ | -10 μAdc, I _C = 0) | V _{(BR)EBO} | -5.0 | - | Vdc |
| Collector Cutoff Current ($V_{CE} = -30$ Vdc, | V _{EB(off)} = -0.5 Vdc) | I _{CEX} | - | -50 | nAdc |
| Collector Cutoff Current ($V_{CB} = -50$ Vdc, $I_E = 0$) ($V_{CB} = -50$ Vdc, $I_E = 0$, $T_A = 125^{\circ}C$) | | I _{CBO} | | -0.010 -10 | μAdc |
| Base Cutoff Current (V _{CE} = -30 Vdc, V _{EE} | _{8(off)} = -0.5 Vdc) | I _{BL} | - | -50 | nAdc |
| ON CHARACTERISTICS | | | - | | |
| $\begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \end{array}$ | e 5) | h _{FE} | 75 100 100 100 50 | - - 300 - | - |
| Collector – Emitter Saturation Voltage (Not $(I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc})$ (Not $(I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc})$ | | V _{CE(sat)} | | -0.4 -1.6 | Vdc |
| Base – Emitter Saturation Voltage (Note 5 $(I_C = -150 \text{ mAdc}, I_B = -15 \text{ mAdc})$ $(I_C = -500 \text{ mAdc}, I_B = -50 \text{ mAdc})$ | 5) | V _{BE(sat)} | | -1.3 -2.6 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | - | - | |
| Current-Gain – Bandwidth Product (Not $(I_C = -50 \text{ mAdc}, V_{CE} = -20 \text{ Vdc}, f = 10)$ | | f _T | 200 | - | MHz |
| Output Capacitance ($V_{CB} = -10$ Vdc, $I_E =$ | = 0, f = 1.0 MHz) | C _{obo} | - | 8.0 | pF |
| Input Capacitance ($V_{EB} = -2.0$ Vdc, $I_C = 0$, f = 1.0 MHz) | | C _{ibo} | - | 30 | |
| SWITCHING CHARACTERISTICS | | | | | |
| Turn-On Time | | t _{on} | _ | 45 | |
| Delay Time | $(V_{CC} = -30 \text{ Vdc}, I_{C} = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$ | t _d | - | 10 | |
| Rise Time | , , , , , , , , , , , , , , , , , , , | t _r | - | 40 | |
| Turn–Off Time | | t _{off} | - | 100 | ns |
| Storage Time | $(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$ | t _s | - | 80 |] |
| Fall Time | -61 -62 -6 | t _f | _ | 30 |] |

5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

6. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.





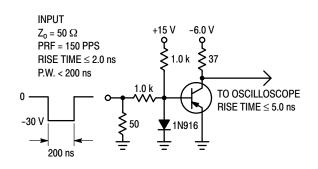
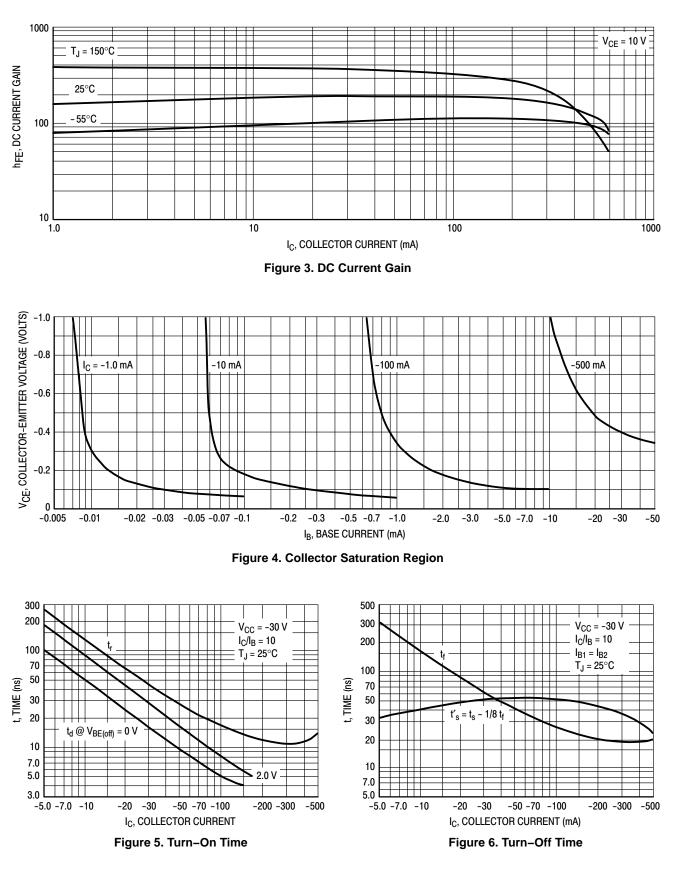


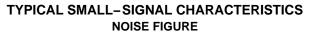
Figure 2. Storage and Fall Time Test Circuit

Share Feedback Your Opinion Matters

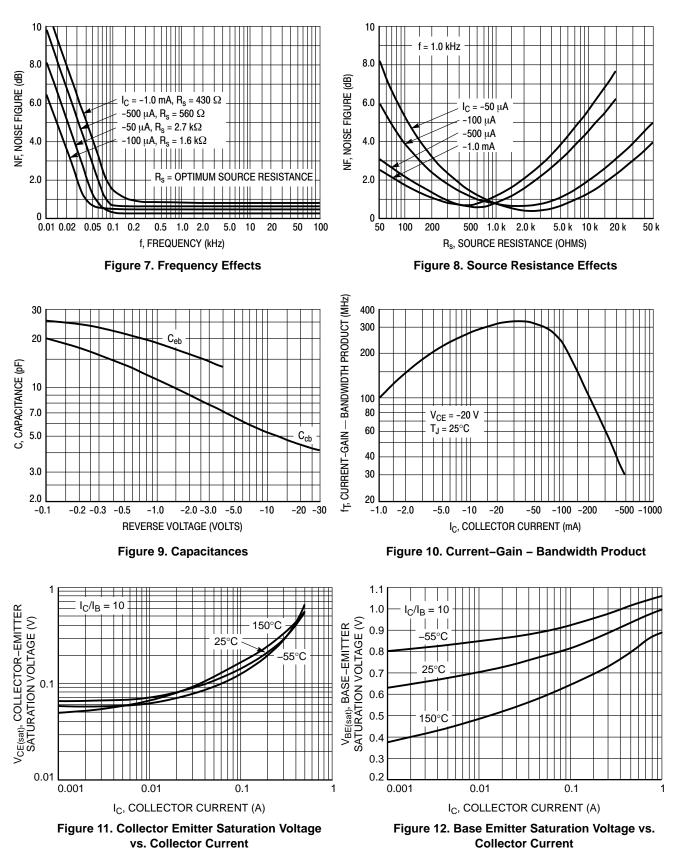
TYPICAL CHARACTERISTICS







 V_{CE} = 10 VDC, T_A = 25°C





TYPICAL SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE

 V_{CE} = 10 VDC, T_A = 25°C

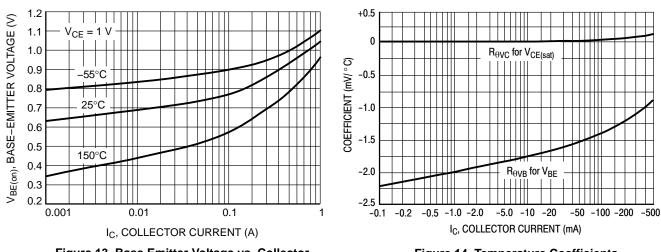




Figure 14. Temperature Coefficients

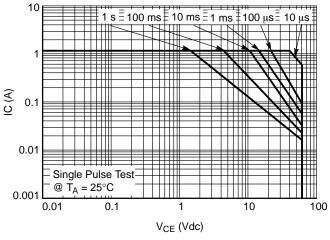


Figure 15. Safe Operating Area



SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

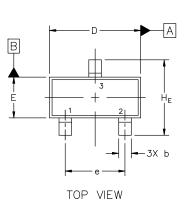


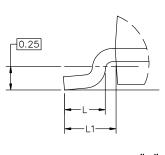
MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

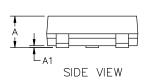
DATE 14 AUG 2024

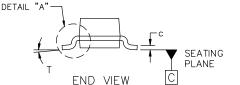
SCALE 4:1









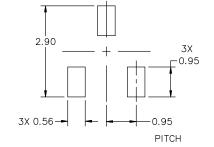




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



| MILLIMETERS | | | | |
|-------------|------|------|------|--|
| DIM | MIN | NOM | МАХ | |
| А | 0.89 | 1.00 | 1.11 | |
| A1 | 0.01 | 0.06 | 0.10 | |
| b | 0.37 | 0.44 | 0.50 | |
| С | 0.08 | 0.14 | 0.20 | |
| D | 2.80 | 2.90 | 3.04 | |
| E | 1.20 | 1.30 | 1.40 | |
| е | 1.78 | 1.90 | 2.04 | |
| L | 0.30 | 0.43 | 0.55 | |
| L1 | 0.35 | 0.54 | 0.69 | |
| ΗE | 2.10 | 2.40 | 2.64 | |
| Т | 0° | | 10° | |

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2.

CONTROLLING DIMENSIONS: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PPOTPUSIONS OR GATE BURRS. 3.

4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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| DESCRIPTION: SOT-23 (TO-236) 2.90x1.30x1.00 1.90P PAGE 1 OF | | PAGE 1 OF 2 | |
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DATE 14 AUG 2024

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | ı | |
|---|---|---|--|------------------|------------------|
| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: | STYLE 13: | STYLE 14: |
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. SOURCE | PIN 1. CATHODE |
| 2. ANODE | 2. SOURCE | 2. CATHODE | 2. CATHODE | 2. DRAIN | 2. GATE |
| 3. CATHODE | 3. GATE | 3. CATHODE-ANODE | 3. ANODE | 3. GATE | 3. ANODE |
| STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: | STYLE 19: | STYLE 20: |
| PIN 1. GATE | PIN 1. ANODE | PIN 1. NO CONNECTION | PIN 1. NO CONNECTION | I PIN 1. CATHODE | PIN 1. CATHODE |
| 2. CATHODE | 2. CATHODE | 2. ANODE | 2. CATHODE | 2. ANODE | 2. ANODE |
| 3. ANODE | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. CATHODE-ANODE | 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3. DRAIN | 3. INPUT | 3. CATHODE | 3. SOURCE | 3. GATE | 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | | |

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